## **FOCUSED ION BEAM SYSTEM: HITACHI FB-2100**

## TEM SAMPLE PREPARATION PROCEDURE

## This procedure assumes the following:

- 1. Bulk sample is loaded on the SEM stage.
- 2. **HV** is on and the tip is conditioned

## **Procedure**

- 1. Find region of interest:
  - a. Select viewing beam 40-0-30.
  - h.

fabrication sub-program.

- 3. Set **magnification** to 2.0K.
- 4. Click the square icon at the top-right corner of the left-hand panel. This captures an image on which to overlay the fabrication diagram.
- 5. Select your deposition and sputtering regions:
  - d. Use **File->Open** to open a pre-

v. Time/Depth/N: determines how deep the cut is made. If your "material" is available as an option, you can use the "depth" setting. Otherwise you must select a cutting time or number of